## NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit driver circuit
- Built in bias resistor ( $R_{1}=10 \mathrm{k} \Omega, R_{2}=47 \mathrm{k} \Omega$ )
- BCR135S: Two internally isolated transistors with good matching in one multichip package
- BCR135S: For orientation in reel see package information below

- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

BCR135 BCR135S
BCR135W


| Type | Marking |  |  |  |  |  |  | Pin Configuration |  |  |  |  | Package |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| BCR135 | WJs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | - | - | - | SOT23 |  |  |  |  |  |
| BCR135S | WJs | $1=\mathrm{E} 1$ | $2=\mathrm{B} 1$ | $3=\mathrm{C} 2$ | $4=\mathrm{E} 2$ | $5=\mathrm{B} 2$ | $6=\mathrm{C} 1$ | SOT363 |  |  |  |  |  |
| BCR135W | WJs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | - | - | - | SOT323 |  |  |  |  |  |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :---: | :--- |
| Collector-emitter voltage | $V_{\mathrm{CEO}}$ | 50 | V |
| Collector-base voltage | $V_{\mathrm{CBO}}$ | 50 |  |
| Input forward voltage | $V_{\mathrm{i}(\mathrm{fwd})}$ | 40 |  |
| Input reverse voltage | $V_{\mathrm{i}(\mathrm{rev})}$ | 6 |  |
| Collector current | $I_{\mathrm{C}}$ | 100 | mA |
| Total power dissipation | $P_{\text {tot }}$ |  | mW |
| BCR135, $T_{\mathrm{S}} \leq 102^{\circ} \mathrm{C}$ |  | 200 |  |
| BCR135S, $T_{\mathrm{S}} \leq 115^{\circ} \mathrm{C}$ |  | 250 |  |
| BCR135W, $T_{\mathrm{S}} \leq 124^{\circ} \mathrm{C}$ |  | 250 |  |
| Junction temperature | $T_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $T_{\text {sta }}$ | $-65 \ldots 150$ |  |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :--- | :--- |
| Junction - soldering point ${ }^{1}$ ) | $R_{\text {thJS }}$ |  | K/W |
| BCR135 |  | $\leq 240$ |  |
| BCR135S |  | $\leq 140$ |  |
| BCR135W |  | $\leq 105$ |  |

[^0]Electrical Characteristics at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | min. | typ. | max. |  |
| DC Characteristics |  |  |  |  |  |
| Collector-emitter breakdown voltage $I_{\mathrm{C}}=100 \mu \mathrm{~A}, I_{\mathrm{B}}=0$ | $V_{\text {(BR)CEO }}$ | 50 | - | - | V |
| Collector-base breakdown voltage $I_{\mathrm{C}}=10 \mu \mathrm{~A}, I_{\mathrm{E}}=0$ | $V_{(\mathrm{BR}) \mathrm{CBO}}$ | 50 | - | - |  |
| Collector-base cutoff current $V_{\mathrm{CB}}=40 \mathrm{~V}, I_{\mathrm{E}}=0$ | ${ }^{\text {CBO }}$ | - | - | 100 | nA |
| Emitter-base cutoff current $V_{E B}=6 \mathrm{~V}, I_{C}=0$ | IEBO | - | - | 167 | $\mu \mathrm{A}$ |
| DC current gain ${ }^{1)}$ $I_{\mathrm{C}}=5 \mathrm{~mA}, V_{\mathrm{CE}}=5 \mathrm{~V}$ | $h_{\text {FE }}$ | 70 | - | - | - |
| Collector-emitter saturation voltage ${ }^{1)}$ $I_{\mathrm{C}}=10 \mathrm{~mA}, I_{\mathrm{B}}=0.5 \mathrm{~mA}$ | $V_{\text {CEsat }}$ | - | - | 0.3 | V |
| Input off voltage $I_{C}=100 \mu \mathrm{~A}, V_{\mathrm{CE}}=5 \mathrm{~V}$ | $V_{i(\text { off })}$ | 0.5 | - | 1 |  |
| Input on voltage $I_{\mathrm{C}}=2 \mathrm{~mA}, V_{\mathrm{CE}}=0.3 \mathrm{~V}$ | $V_{\mathrm{i}(\mathrm{on})}$ | 0.5 | - | 1.4 |  |
| Input resistor | $R_{1}$ | 7 | 10 | 13 | $\mathrm{k} \Omega$ |
| Resistor ratio | $R_{1} / R_{2}$ | 0.19 | 0.21 | 0.24 | - |
| AC Characteristics |  |  |  |  |  |
| Transition frequency $I_{\mathrm{C}}=10 \mathrm{~mA}, V_{\mathrm{CE}}=5 \mathrm{~V}, f=100 \mathrm{MHz}$ | $f_{\text {T }}$ | - | 150 | - | MHz |
| Collector-base capacitance $V_{\mathrm{CB}}=10 \mathrm{~V}, f=1 \mathrm{MHz}$ | $C_{\text {cb }}$ | - | 3 | - | pF |

DC current gain $h_{\text {FE }}=f\left(I_{C}\right)$
$V_{C E}=5 \mathrm{~V}$ (common emitter configuration)


Input on Voltage $V_{i_{(o n)}}=f\left(I_{C}\right)$
$V_{C E}=0.3 \mathrm{~V}$ (common emitter configuration)


## Collector-emitter saturation voltage

$V_{\text {CEsat }}=f\left(I_{\mathrm{C}}\right), I_{\mathrm{C}} I_{\mathrm{B}}=20$


Input off voltage $V_{i(\text { off })}=f\left(I_{\mathrm{C}}\right)$
$V_{C E}=5 \mathrm{~V}$ (common emitter configuration)


Total power dissipation $P_{\text {tot }}=f\left(T_{\mathrm{S}}\right)$ BCR135


Total power dissipation $P_{\text {tot }}=f\left(T_{\mathrm{S}}\right)$ BCR135W


Total power dissipation $P_{\text {tot }}=f\left(T_{\mathrm{S}}\right)$ BCR135S


Permissible Pulse Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$ BCR135


Permissible Pulse Load
$P_{\text {totmax }} / P_{\text {totDC }}=f\left(t_{\mathrm{p}}\right)$
BCR135


Permissible Pulse Load
$P_{\text {totmax }} / P_{\text {totDC }}=f\left(t_{\mathrm{p}}\right)$
BCR135S


Permissible Puls Load $R_{\text {th } J S}=f\left(t_{\mathrm{p}}\right)$ BCR135S


Permissible Puls Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$ BCR135W


Permissible Pulse Load


Package Outline


1) Lead width can be 0.6 max. in dambar area

Foot Print


Marking Layout (Example)


## Standard Packing

Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel


Package Outline


Foot Print


Marking Layout (Example)


## Standard Packing

Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel


## Package Outline



Foot Print


## Marking Layout (Example)

Small variations in positioning of
Date code, Type code and Manufacture are possible.


## Standard Packing

Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel
For symmetric types no defined Pin 1 orientation in reel.


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[^0]:    ${ }^{1}$ For calculation of $R_{\text {thJA }}$ please refer to Application Note AN077 (Thermal Resistance Calculation)

